

MA2S376

Silicon epitaxial planar type

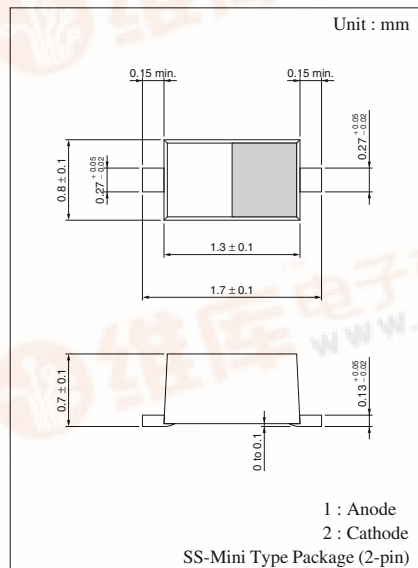
For VCO of a UHF radio

■ Features

- Small series resistance r_D
- SS-mini type package, allowing downsizing of equipment and automatic insertion through the taping package

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Reverse voltage (DC)	V_R	6	V
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$



Marking Symbol: H

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse current (DC)	I_R	$V_R = 6\text{ V}$			10	nA
Diode capacitance	$C_{D(1V)}$	$V_R = 1\text{ V}, f = 1\text{ MHz}$	14.00		16.00	pF
	$C_{D(3V)}$	$V_R = 3\text{ V}, f = 1\text{ MHz}$	6.80		8.90	pF
Series resistance*	r_D	$C_D = 9\text{ pF}, f = 470\text{ MHz}$			0.3	Ω

Note) 1. Rated input/output frequency: 470 MHz

2. *: r_D measuring instrument: YHP MODEL 4191A RF IMPEDANCE ANALYZER

